### **UF800 THRU UF808**

## GM Garbo Micro Semiconductor

# ULTRAFAST SWITCHING RECTIFIER VOLTAGE - 50 to 800 Volts URRENT - 8.0 Amperes

#### **FEATURES**

- Plastic package has Underwriters Laboratory
  Flammability Classification 94V-O Utilizing
  Flame Retardant Epoxy Molding Compound
- ●Exceeds environmental standards of MIL-S-19500/228
- Low power loss, high efficiency
- Low forward voltage, high current capability
- High surge capacity
- Ultra Fast recovery times high voltage

#### **MECHANICAL DATA**

Case: TO-220AC molded plastic

Terminals: Lead solderable per MIL-STD-202, Method 208

Polarity: As marked Mounting Position: Any

Weight: 0.08 ounce, 2.24 gram

**TO-220AC** 

Dimensions in inches and (millimeters)

.1 (2.54)

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25  $\square$ J ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

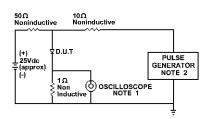
For capacitive load, derate current by 20%

1 or supusitive load, derate surrent by 2070								
TYPE NUMBER	UF800	UF801	UF802	UF803	UF804	UF806	UF808	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	V
Maximum RMS Voltage	35	70	140	210	280	420	560	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	V
Maximum Average Forward Rectified	8.0							Α
Current .375"(9.5mm) lead length @ $T_C$ =100 °C								
Peak Forward Surge Current, 8.3ms single half sine wave superimposed on rated load(JECEC method)	125							Α
Maximum Instantaneous Forward Voltage at 8.0A	1.0			1.3		1.7		V
Maximum DC Reverse Current @T <sub>A</sub> =25℃	10.0							uA
at Rated DC Blocking Voltage @T <sub>A</sub> =125℃	500							uA
Maximum Reverse Recovery Time(Note 1)	50 100					ns		
Typical Junction capacitance (Note 2)	80 50					50	₽F	
Typical Junction Resistance (Note 2) R KJA	15							°C /W
Operating and Storage Temperature Range T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150							°C

#### NOTES:

- 1. Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1A, I<sub>rr</sub>=0.25A
- 2. Measured at 1 MHz and applied reverse voltage of 4.0 VDC
- 3. Thermal resistance from junction to ambient and from junction to lead length 0.375"(9.5mm) P.C.B. mounted

### RATING AND CHARACTERISTIC CURVES UF800 THRU UF808



NOTE:1.Rise Time = 7ns max. Input Impedance = 1 megohm. 22pF 2.Rise Time = 10ns max.

Source Impedance = 50 Ohms

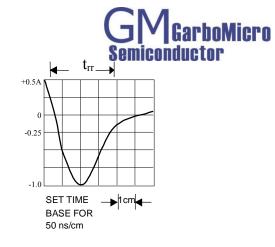


Fig. 1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

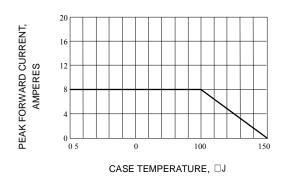
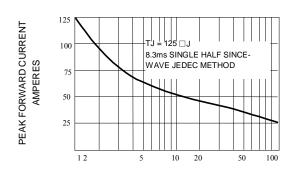


Fig. 1-TYPICAL FORWARD CURRENT DERATING CURVE



NUMBER OF CYCLES AT 60Hz

Fig. 3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

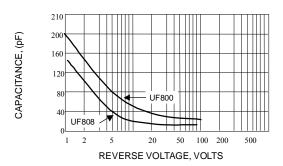
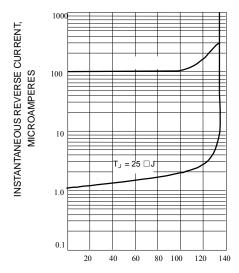


Fig. 4-TYPICAL JUNCTION CAPACITANCE



PERCENT OF RATED PEAK REVERSE VOLTAGE

Fig. 2-TYPICAL REVERSE CHARACTERISTICS

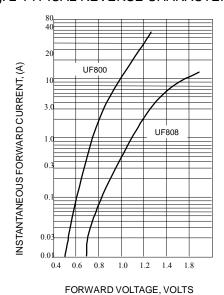


Fig. 5-TYPICAL FORWARD CURRENT